

## Preamplifier for IR Remote Control

### Description

The IC U2535B-FP is a complete IR receiver for data communication. The PIN-photodiode converts the transmitted IR-telegram into the electronic input signals. This is separated by a special input circuit. The characteristics (filter, gain) of the following amplifier is

determined by external components. The signal detector, consisting of a comparator, an integrator and a Schmitt trigger, forms the input signal to an output pulse that can be interfaced to a microcomputer.

### Features

- Low current requirement (typical 260  $\mu$ A/ 12 V)
- Carrier frequencies between 20 to 100 kHz
- Supply voltages: 5 or 7 to 16 V with internal stabilisation
- Filter characteristics and gain are specified by few external components
- Demodulator with Schmitt-trigger
- Open collector output

### Applications

- Keyless entry
- Remote control
- Wireless data transfer

Case: SO8

### Block Diagram

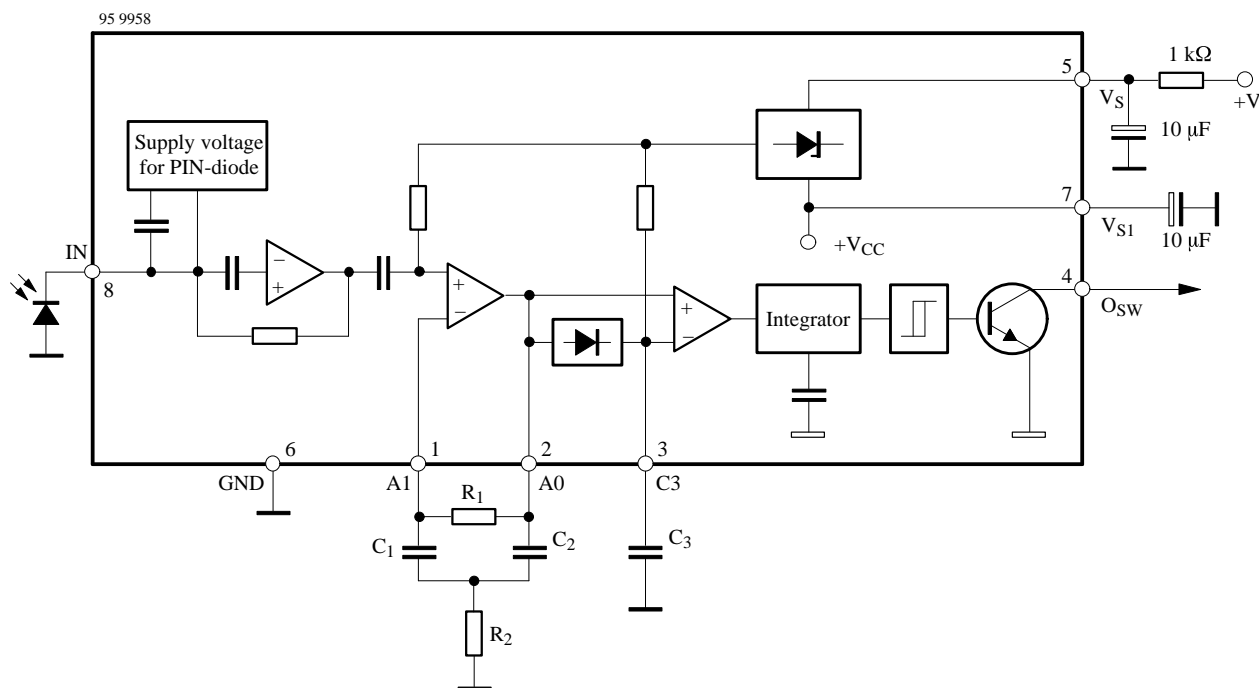
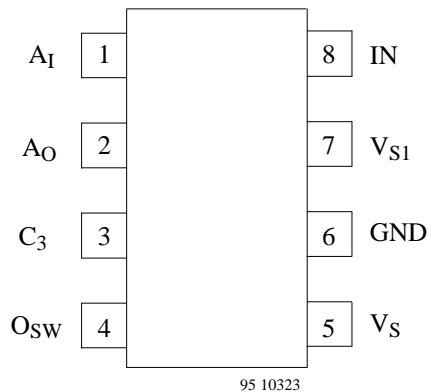


Figure 1. Block diagram

## Pin Description



Pin	Symbol	Function
1	A <sub>I</sub>	Inverting input of band pass amplifier, pin connection for external filter function
2	A <sub>O</sub>	Output of band pass amplifier
3	C <sub>3</sub>	Capacitor at Pin 3 to reject (suppress) ripple during transmission, also functions as delay time for reference voltage of the comparator
4	O <sub>SW</sub>	Switching output It is an open collector output which switches with time delay and goes LOW (transistor switched ON), when the signal is identified at Pin 2.
5	V <sub>S</sub>	Supply voltage The integrated Z-diode (typical 17 V) protects the circuit against positive voltage spikes
6	GND	Ground
7	V <sub>S1</sub>	Unregulated supply voltage for 5 V operation
8	IN	Input connection for photodiode with regulated bias voltage

## Absolute Maximum Ratings

Reference point Pin 6, unless otherwise specified

Parameters	Symbol	Value	Unit
Supply voltage range	V <sub>S</sub>	-0.3 to +16	V
Supply currents: tp ≤ 250 ms	I <sub>S</sub>	20	mA
	i <sub>S</sub>	150	mA
Input voltages	V <sub>A(I)</sub>	-0.3 to 5	V
	V <sub>O(SW)</sub>	-0.3 to 16	V
	V <sub>IN</sub>	-0.3 to 5	V
Output currents	I <sub>O</sub>	±5	mA
Junction temperature	T <sub>j</sub>	125	°C
Storage temperature range	T <sub>stg</sub>	-40 to +125	°C
Ambient temperature range	T <sub>amb</sub>	-40 to +105	°C

## Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient	R <sub>thJA</sub>	180	K/W

## Electrical Characteristics

$T_{amb} = 25^{\circ}\text{C}$ , reference point Pin 6, test circuit, unless otherwise specified

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Supply currents	$V_{S1} = 5\text{ V}$ , $I_{IN} = 0$ , Pin 7	$I_{S1}$	140		200	$\mu\text{A}$
	$V_S = 12\text{ V}$ , $I_{IN} = 0$ , Pin 5	$I_S$	200		320	$\mu\text{A}$
Internal stabilisation	$V_S = 12\text{ V}$ , $I_{IN} = 0$ , Pin 7	$V_{S1}$	4.9		5.4	V
Maximum input current	$V_{S1} = 5\text{ V}$ , $V_{IN} = 0$ , Pin 8	$-I_{IN}$	0.8		1.2	mA
Low level voltage	$V_{S1} = 5\text{ V}$ , $I_{OL} = 0.5\text{ mA}$ Pin 4	$V_{OL}$			0.2	V
Leakage current	$V_{S1} = 5\text{ V}$ , $V_0 = 12\text{ V}$ , Pin 4	$I_{OH}$			1	$\mu\text{A}$
<b>Input stage, amplifier</b>						
Cut-off frequency		$f_L$			15	kHz
		$f_H$	100			kHz
Gain	$V_i = 2\text{ mV}_{\text{rms}}$ , $f = 40\text{ kHz}$ $f = 100\text{ kHz}$	$G_v$	47	50		dB
		$G_v$	46	49		dB
<b>Detector</b>						
Threshold voltage	$t_d \leq 200\ \mu\text{s}$ , $f = 40\text{ kHz}$ , Pin 2	$V_{A0}$		150		$\text{mV}_{\text{rms}}$
Delay time	$f = 40\text{ kHz}$ , $V_{A0} = 1\text{ V}_{\text{rms}}$ see figure 3	$t_d$	50	90		$\mu\text{s}$
Storage time	$f = 40\text{ kHz}$ , $V_{A0} = 1\text{ V}_{\text{rms}}$ see figure 3	$t_s$	100		150	$\mu\text{s}$

## Test Circuit

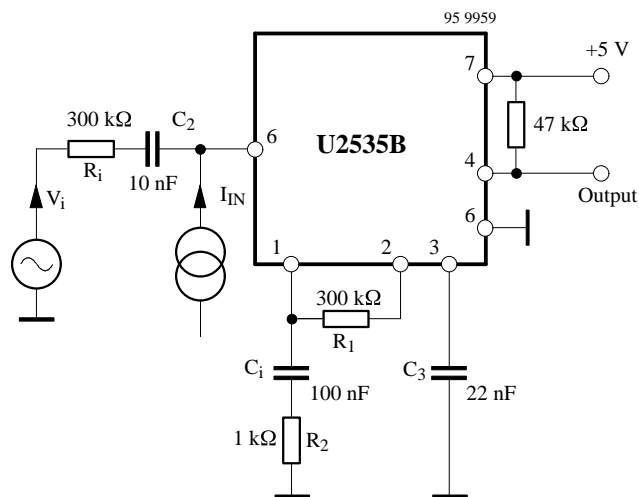


Figure 2.

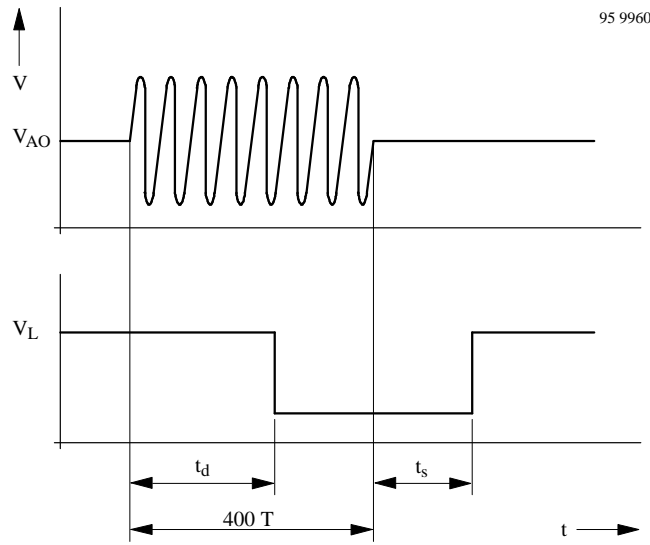


Figure 3.

## Application Circuit

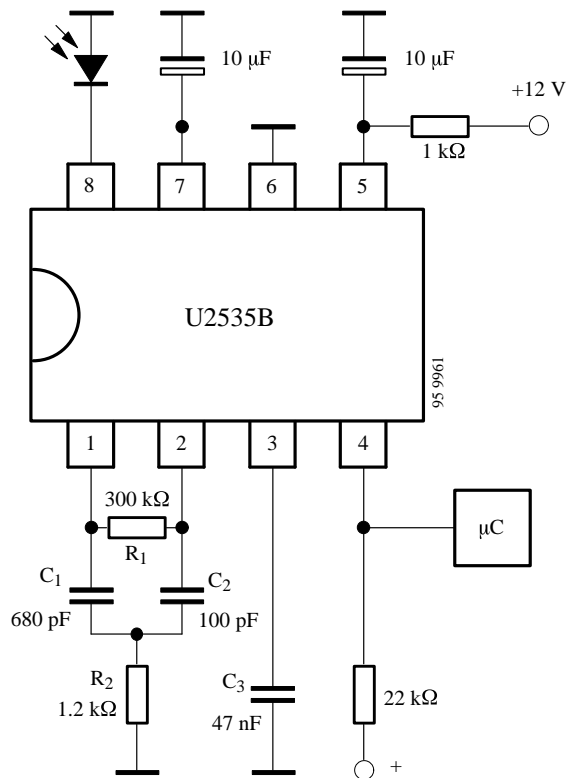


Figure 4.

## Band Pass Filter Design

### Center frequency

$$f_0 = \frac{1}{2\pi \sqrt{R_1 \times C_1 \times R_2 \times C_2}}$$

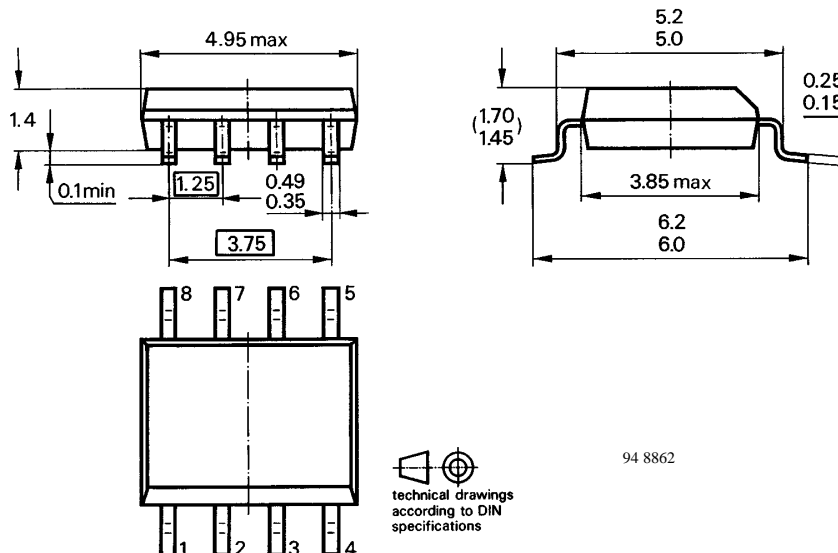
$$\text{GAIN} \approx \frac{R_1 \times C_1}{R_2 (C_1 + C_2)} \quad \begin{array}{l} R_1 \gg R_2 \\ C_1 \cong C_2 \end{array}$$

$$\text{Bandwidth} \approx \frac{C_1 + C_2}{2\pi \times R_1 \times C_1 \times C_2} \quad \text{BW} \ll f_0$$

**Note:**  $R_1$  should be about 300 k $\Omega$ .  
Results can be influenced by feedback (Pin 2  $\rightarrow$  Pin 8)

## Dimensions in mm

Package: SO 8



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2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

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1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

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